

# No. 2013HAC00032

For

## **TCT Mobile Limited**

## HSUPA/HSDPA/UMTS Triband / GSM quadband mobile phone

**Mode Name: HERO** 

Marketing Name: ONE TOUCH 8020A

With

**Hardware Version: PIO** 

Software Version: vBAM

FCC ID: RAD398

**Results Summary: M Category = M4** 

Issued Date: 2014-01-17



#### Note:

The test results in this test report relate only to the devices specified in this report. This report shall not be reproduced except in full without the written approval of TMC Beijing.

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# **Revision Version**

Report Number	Revision	Date	Memo
2013HAC00032	00	2014-01-10	Initial creation of test report
2013HAC00032	01	2014-01-17	Add the information of HAC test with Flip cover



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## 1 Test Laboratory

## 1.1 Testing Location

Company Name: TMC Beijing, Telecommunication Metrology Center of MIIT Address: No 52, Huayuan beilu, Haidian District, Beijing, P.R.China

Postal Code: 100191

Telephone: +86-10-62304633 Fax: +86-10-62304793

### 1.2 Testing Environment

Temperature:  $18^{\circ}\text{C} \sim 25^{\circ}\text{C}$ , Relative humidity:  $30\% \sim 70\%$  Ground system resistance:  $< 0.5 \ \Omega$ 

Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.

## 1.3 Project Data

Project Leader: Qi Dianyuan
Test Engineer: Lin Hao

Testing Start Date: January 04, 2014
Testing End Date: January 04, 2014

### 1.4 Signature

Lin Hao

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

Xiao Li

Deputy Director of the laboratory (Approved this test report)



# **2 Client Information**

# 2.1 Applicant Information

Company Name:	TCT Mobile Limited			
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Address /Post:	Pudong Area Shanghai, P.R. China. 201203			
City:	ShangHai			
Postal Code:	201203			
Country:	P.R.China			
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## 2.2 Manufacturer Information

Company Name:	TCT Mobile Limited			
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Address /Post.	Pudong Area Shanghai, P.R. China. 201203			
City:	ShangHai			
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Email:	zhizhou.gong@jrdcom.com			
Telephone:	0086-21-61460890			
Fax:	0086-21-61460602			



# 3 Equipment Under Test (EUT) and Ancillary Equipment (AE)

#### 3.1 About EUT

Description:	HSUPA/HSDPA/UMTS Triband / GSM quadband mobile phone
Mode Name:	HERO
Marketing Name:	ONE TOUCH 8020A
Operating mode(s):	GSM 850/900/1800/1900, WCDMA 850/1900/2100, BT, Wi-Fi

## 3.2 Internal Identification of EUT used during the test

EUT ID*	IMEI	HW Version	SW Version
EUT1	013802001089733	PIO	vBAM
EUT2	013802001001142	PIO	vBAM

<sup>\*</sup>EUT ID: is used to identify the test sample in the lab internally.

**Note:** It is performed to test HAC with the EUT1 and conducted power with the EUT2.

## 3.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
AE1	Battery	CAC3380001C2	/	SCUD

<sup>\*</sup>AE ID: is used to identify the test sample in the lab internally.

## 3.4 Air Interfaces / Bands Indicating Operating Modes

Air-interface	Band(MHz)	Туре	C63.19/ tested	Simultaneous Transmissions Note: Not to be tested	Concurrent single transmission	Reduced power	Voice Over Digital Transport (Data)								
	850			Yes	Yes										
GSM		VO	Yes	WIFI or BT	GPRS/EDGE, WIFI, BT	No	NA								
GGIVI	1900				Not rated										
	GPRS/EDGE	DT	NA	NA	Yes* see note	NA	NA								
MCDMA	850	7/0	V/D Yes	Yes	Yes	No	NA								
WCDMA	1900	V/D	162	WIFI or BT	WIFI, BT										
WIFI	2450	0.450	2450	2450	2450	2450	2450	2450	2450	DT	DT NA	Yes	NA* NA		NA
VVIFI		וט	NA	GSM or WCDMA	NA* NA	INA	INA								
DT	2450	2450 V/D	NA	Yes	Yes	NΙΔ	NA								
BT	2450			GSM or WCDMA	GPRS/EDGE, WCDMA	INA									

VO: Voice CMRS/PSTN Service Only

V/D: Voice CMRS/PSTN and Data Service

DT: Digital Transport

<sup>\*</sup> HAC Rating was not based on concurrent voice and data modes, Non current mode was found to represent worst case rating for both M and T rating



## 3.5 Accessory

There is a kind of accessory (flip cover) with conductive materials, and support wireless charging. According to the KDB 648474 D03, because the flip cover support wireless charging, the handset must be evaluated with both the normal and wireless charging battery covers to determine the worst case HAC rating.

# Wireless charging Flipcover CMF

Standard: Bluish Black with Hair Line Brush Texture



Constituents of the flip cover



## **4 CONDUCTED OUTPUT POWER MEASUREMENT**

## 4.1 Summary

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured output power should be greater and within 5% than EMI measurement.

#### 4.2 Conducted Power

GSM	Conducted Power (dBm)						
850MHz	Channel 251(848.8MHz)	Channel 190(836.6MHz)	Channel 128(824.2MHz)				
OSUMINZ	32.90	32.91	32.88				
CCM		Conducted Power (dBm)					
GSM 1900MHz	Channel 810(1909.8MHz)	Channel 661(1880MHz)	Channel 512(1850.2MHz)				
TSOUNTE	29.55	29.64	29.54				
WCDMA	Conducted Power (dBm)						
850MHz	Channel 4233(846.6MHz)	Channel 4182(836.4MHz)	Channel 4132(826.4MHz)				
OJUMI12	22.98	23.28	23.27				
WCDMA	Conducted Power (dBm)						
1900MHz	Channel 9538(1907.6MHz)	Channel 9400(1880MHz)	Channel 9262(1852.4MHz)				
I SUUIVINZ	22.41	22.86	22.81				

## 5. Reference Documents

## 5.1Reference Documents for testing

The following document listed in this section is referred for testing.

Reference	Title	Version
ANSI C63.19-2007	American National Standard for Methods of Measurement	2007
	of Compatibility between Wireless Communication Devices	Edition
	and Hearing Aids	
FCC 47 CFR §20.19	Hearing Aid Compatible Mobile Headsets	/
KDB 285076 D01	Equipment Authorization Guidance for Hearing Aid	v03
	Compatibility	



### **6 OPERATIONAL CONDITIONS DURING TEST**

#### 6.1 HAC MEASUREMENT SET-UP

These measurements are performed using the DASY5 NEO automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and remote control, is used to drive the robot motors. The PC consists of the HP Intel Core2 1.86 GHz computer with Windows XP system and HAC Measurement Software DASY5 NEO, A/D interface card, monitor, mouse, and keyboard. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

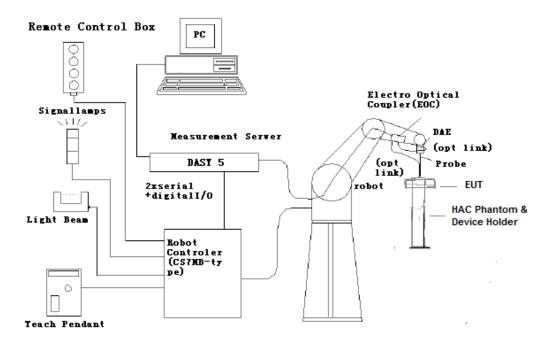


Fig. 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



## 6.2 Probe Specification

#### 6.2.1 E-Field Probe Description

Construction One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%,

k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity  $\pm 0.2$  dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements

Fast automatic scanning in phantoms

### 6.2.2 H-Field Probe Description

Construction Three concentric loop sensors with 3.8 mm loop diameters

Resistively loaded detector diodes for linear response

Built-in shielding against static charges

PEEK enclosure material (resistant to organic solvents,

e.g., glycolether)

Frequency 200 MHz to 3 GHz (absolute accuracy ± 6.0%, k=2); Output

linearized

Directivity ± 0.2 dB (spherical isotropy error)

Dynamic Range 10 mA/m to 2 A/m at 1 GHz

E-Field Interference < 10% at 3 GHz (for plane wave)

Dimensions Overall length: 330 mm (Tip: 40 mm)

Tip diameter: 6 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 3 mm

Application General magnetic near-field measurements up to 3 GHz (in

air or liquids)

Field component measurements
Surface current measurements

Low interaction with the measured field



[ER3DV6]



[H3DV6]



#### 6.3 Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions:  $370 \times 370 \times 370 \text{ mm}$ ).

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field  $<\pm 0.5$  dB.



Fig. 2 HAC Phantom & Device Holder

### 6.4 Robotic System Specifications

### **Specifications**

Positioner: Stäubli Unimation Corp. Robot Model: RX160L

Repeatability: ±0.02 mm

No. of Axis: 6

#### **Data Acquisition Electronic (DAE) System**

**Cell Controller** 

Processor: Intel Core2 Clock Speed: 1.86 GHz

**Operating System:** Windows XP

**Data Converter** 

Features: Signal Amplifier, multiplexer, A/D converter, and control logic

Software: DASY5 software

**Connecting Lines:** Optical downlink for data and status info.

Optical uplink for commands and clock



### **7 EUT ARRANGEMENT**

#### 7.1 WD RF Emission Measurements Reference and Plane

Figure 4 illustrates the references and reference plane that shall be used in the WD emissions measurement.

- The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.
- The grid is centered on the audio frequency output transducer of the WD (speaker or T-coil).
- The grid is located by reference to a reference plane. This reference plane is the planar area that contains the highest point in the area of the WD that normally rests against the user's ear
- The measurement plane is located parallel to the reference plane and 15 mm from it, out from the phone. The grid is located in the measurement plane.

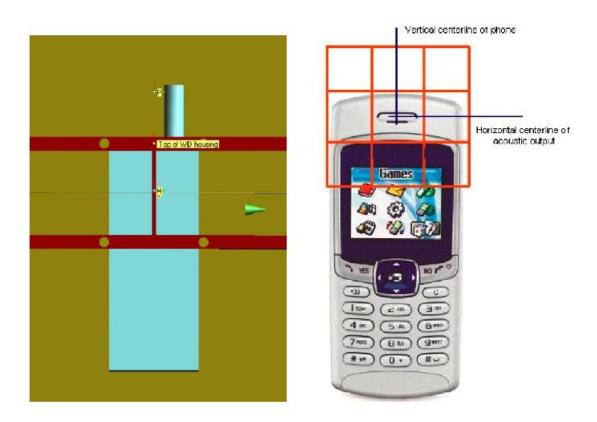


Fig. 3 WD reference and plane for RF emission measurements



## **8 SYSTEM VALIDATION**

#### 8.1 Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 D.5 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical and magnetic output. Position the E-field and H-field probes so that:

- The probes and their cables are parallel to the coaxial feed of the dipole antenna
- The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions
- The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements.

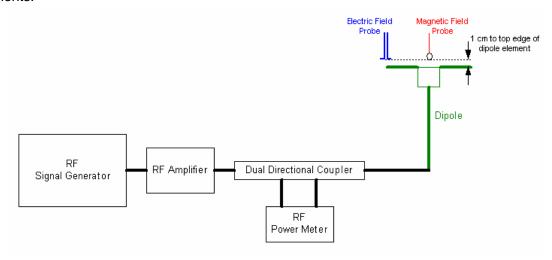


Fig. 4 Dipole Validation Setup

#### 8.2 Validation Result

	E-Field Scan						
Mode	Frequency	Input	Power	Measured <sup>1</sup>	Target <sup>2</sup>	Deviation <sup>3</sup>	Limit <sup>4</sup>
	(MHz)	(mW)		Value(V/m)	Value(V/m)	(%)	(%)
CW	835	100		169.5	171.9	-1.40	±25
CW	1880	100		141.3	142.7	-0.98	±25
				H-Field Scan			
Mode	Frequency	Input	Power	Measured	Target	Deviation	Limit
	(MHz) (mW) Value(A/m) Value(A/m) (%) (%)						
CW	835	100		0.469	0.461	1.74	±25
CW	1880	100		0.456	0.466	-2.15	±25

#### Notes:

- 1. Please refer to the attachment for detailed measurement data and plot.
- 2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
- 3. Deviation (%) = 100 \* (Measured value minus Target value) divided by Target value.
- 4. ANSI C63.19 requires values within  $\pm$  25% are acceptable, of which 12% is deviation and 13% is measurement uncertainty. Values independently validated for the dipole actually used in the measurements should be used, when available.



## 9 Probe Modulation Factor

The Probe Modulation Factor (PMF) is defined as the ratio of the field readings for a CW and a modulated signal with the equivalent Field Envelope Peak as defined in ANSI C63.19 (Chapter C.3.1). Calibration shall be made of the modulation response of the probe and its instrumentation chain. This Calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type.

#### 9.1 Modulation Factor Test Procedure

This may be done using the following procedure:

- 1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna, as illustrated in Figure 6.
- 2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.
- 3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna
- 4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
- 5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
- 6. Record the reading of the probe measurement system of the unmodulated signal.
- 7. The ratio, in linear units, of the probe reading in Step 6) to the reading in Step 3) is the E-field modulation factor.  $PMF_E = E_{CW} / E_{mod} (PMF_H = H_{CW} / H_{mod})$
- 8. Repeat the previous steps using the H-field probe, except locate the probe at the center of the dipole.



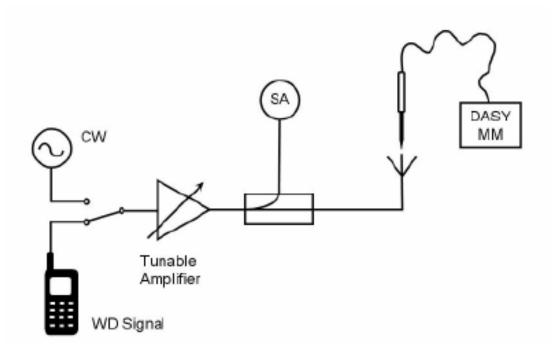


Fig. 5 Probe Modulation Factor Test Setup

## 9.2 Modulation Factor

### 9.2.1 E-Field

Frequency	Mode	Input Power	E-Field Measured Value	Probe Modulation
(MHz)		(mW)	(V/m)	Factor
	CW	100	169.5	1
835	WCDMA	100	167.0	1.003
	GSM	100	59.0	2.875
	CW	100	141.3	1
1880	WCDMA	100	140.6	1.005
	GSM	100	49.0	2.884

## 9.2.2 H-Field

Frequency	Mode	Input Power	H-Field Measured Value	Probe Modulation
(MHz)		(mW)	(A/m)	Factor
	CW	100	0.469	1
835	WCDMA	100	0.466	1.006
	GSM	100	0.163	2.875
	CW	100	0.456	1
1880	WCDMA	100	0.454	1.005
	GSM	100	0.159	2.868



## **10 RF TEST PROCEDUERES**

## The evaluation was performed with the following procedure:

- 1) Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2) Position the WD in its intended test position. The gauge block can simplify this positioning. Note that a separate E-field and H-field gauge block will be needed if the center of the probe sensor elements are at different distances from the tip of the probe.
- 3) Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4) The center sub-grid shall centered on the center of the T-Coil mode axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the 50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5) Record the reading.
- 6) Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7) Identify the five contiguous sub-grids around the center sub-grid with the lowest maximum field strength readings. Thus the six areas to be used to determine the WD's highest emissions are identified and outlined for the final manual scan. Please note that a maximum of five blocks can be excluded for both E-field and H-field measurements for the WD output being measured. Stated another way, the center sub-grid and three others must be common to both the E-field and H-field measurements.
- 8) Identify the maximum field reading within the non-excluded sub-grids identified in Step 7)
- 9) Convert the maximum field strength reading identified in Step 8) to V/m or A/m, as appropriate. For probes which require a probe modulation factor, this conversion shall be done using the appropriate probe modulation factor and the calibration.
- 10) Repeat Step 1) through Step 10) for both the E-field and H-field measurements.
- 11) Compare this reading to the categories in ANSI C63.19 Clause 7 and record the resulting category. The lowest category number listed in 7.2, Table 7.4, or Table 7.5 obtained in Step 10) for either E- or H-field determines the M category for the audio coupling mode assessment. Record the WD category rating.



# 11 HAC RF TEST DATA SUMMARY

# 11.1 Measurement Results (E-Field)

Freq	luency	AWF	Measured Value	Power Drift	Category					
MHz	Channel		(V/m)	(dB)						
	GSM 850									
848.8	251	-5	109.2	-0.02	M4(see Fig B.1)					
836.6	190	-5	111.3	-0.09	M4(see Fig B.2)					
824.2	128	-5	104.4	-0.07	M4(see Fig B.3)					
			GSM 190	0						
1909.8	810	-5	39.53	-0.00	M4(see Fig B.4)					
1880	661	-5	44.13	-0.04	M4(see Fig B.5)					
1850.2	512	-5	45.52	0.02	M4(see Fig B.6)					
			WCDMA 8	50						
846.6	4233	0	33.12	0.02	M4(see Fig B.7)					
836.4	4182	0	37.63	-0.00	M4(see Fig B.8)					
826.4	4132	0	37.76	0.00	M4(see Fig B.9)					
			WCDMA 19	900						
1907.6	9538	0	16.27	-0.03	<b>M4</b> (see Fig B.10)					
1880	9400	0	19.54	0.18	<b>M4</b> (see Fig B.11)					
1852.4	9262	0	20.40	0.05	<b>M4</b> (see Fig B.12)					

## 11.2 Measurement Results (H-Field)

Freq	uency	AWF	Measured Value	Power Drift	Category				
MHz	Channel		(A/m)	(dB)					
GSM 850									
848.8	251	-5	0.08813	-0.02	<b>M4</b> (see Fig B.13)				
836.6	190	-5	0.09286	-0.11	<b>M4</b> (see Fig B.14)				
824.2	128	-5	0.09373	0.19	<b>M4</b> (see Fig B.15)				
			GSM 190	0					
1909.8	810	-5	0.1102	-0.03	<b>M4</b> (see Fig B.16)				
1880	661	-5	0.1125	-0.07	<b>M4</b> (see Fig B.17)				
1850.2	512	-5	0.1108	0.04	<b>M4</b> (see Fig B.18)				
			WCDMA 8	50					
846.6	4233	0	0.06184	-0.06	<b>M4</b> (see Fig B.19)				
836.4	4182	0	0.05757	0.18	<b>M4</b> (see Fig B.20)				
826.4	4132	0	0.06413	0.02	<b>M4</b> (see Fig B.21)				
	WCDMA 1900								
1907.6	9538	0	0.04702	0.00	<b>M4</b> (see Fig B.22)				
1880	9400	0	0.05842	0.03	<b>M4</b> (see Fig B.23)				
1852.4	9262	0	0.06610	-0.19	<b>M4</b> (see Fig B.24)				



## 11.3 Total M-rating

Mode	Maximum value of	Maximum value of	E-Field M	H-Field M	Total M
	peak Total E-Field	peak Total H-Field	Rating	Rating	Rating
	(V/m)	(A/m)			
GSM	111.3	0.09373	M4	M4	M4(see Fig
850	111.3	0.09373	(AWF -5 dB)	(AWF -5 dB)	B.25)
GSM	45.52	0.1125	M4	M4	M4(see Fig
1900	45.52	0.1125	(AWF -5 dB)	(AWF -5 dB)	B.26)
WCDMA	37.76	0.06413	M4	M4	M4(see Fig
850	37.70	0.00413	(AWF 0 dB)	(AWF 0 dB)	B.27)
WCDMA	20.52	0.06610	M4	M4	M4(see Fig
1900	20.52	0.06610	(AWF 0 dB)	(AWF 0 dB)	B.28)

# 11.4 Measurement Results (E-Field) with Flip cover

Freq	luency	AWF	Measured Value	Power Drift	Category					
MHz	Channel		(V/m)	(dB)						
	GSM 850									
848.8	251	-5	97.32	-0.06	<b>M4</b> (see Fig B.29)					
836.6	190	-5	106.1	-0.02	<b>M4</b> (see Fig B.30)					
824.2	128	-5	102.2	-0.03	<b>M4</b> (see Fig B.31)					
			GSM 190	0						
1909.8	810	-5	31.35	-0.00	<b>M4</b> (see Fig B.32)					
1880	661	-5	35.26	0.11	<b>M4</b> (see Fig B.33)					
1850.2	512	-5	35.78	-0.07	<b>M4</b> (see Fig B.34)					
			WCDMA 8	50						
846.6	4233	0	30.67	-0.02	<b>M4</b> (see Fig B.35)					
836.4	4182	0	36.78	0.04	<b>M4</b> (see Fig B.36)					
826.4	4132	0	37.82	-0.04	<b>M4</b> (see Fig B.37)					
			WCDMA 19	900						
1907.6	9538	0	13.11	-0.10	<b>M4</b> (see Fig B.38)					
1880	9400	0	13.82	-0.11	<b>M4</b> (see Fig B.39)					
1852.4	9262	0	14.65	0.06	<b>M4</b> (see Fig B.40)					



## 11.5 Measurement Results (H-Field) with Flip cover

Freq	luency	AWF	Measured Value	Power Drift	Category
MHz	Channel		(A/m)	(dB)	
848.8	251	-5	0.1829	-0.02	<b>M4</b> (see Fig B.41)
836.6	190	-5	0.2101	-0.01	<b>M4</b> (see Fig B.42)
824.2	128	-5	0.1931	-0.11	<b>M4</b> (see Fig B.43)
			GSM 190	0	
1909.8	810	-5	0.08887	0.06	<b>M4</b> (see Fig B.44)
1880	661	-5	0.08936	-0.12	<b>M4</b> (see Fig B.45)
1850.2	512	-5	0.08564	0.15	<b>M4</b> (see Fig B.46)
			WCDMA 8	350	
846.6	4233	0	0.05205	0.04	<b>M4</b> (see Fig B.47)
836.4	4182	0	0.06257	-0.02	<b>M4</b> (see Fig B.48)
826.4	4132	0	0.06191	0.00	<b>M4</b> (see Fig B.49)
			WCDMA 19	900	
1907.6	9538	0	0.03533	0.02	<b>M4</b> (see Fig B.50)
1880	9400	0	0.03733	0.04	<b>M4</b> (see Fig B.51)
1852.4	9262	0	0.03795	-0.15	<b>M4</b> (see Fig B.52)

## 11.6 Total M-rating with Flip cover

Mode	Maximum value of Maximum value of		E-Field M	H-Field M	Total M
	peak Total E-Field	peak Total H-Field	Rating	Rating	Rating
	(V/m)	(A/m)			
GSM	106.1	0.2101	M4	M4	M4(see Fig
850	100.1	0.2101	(AWF -5 dB)	(AWF -5 dB)	B.53)
GSM	35.78	0.00026	M4	M4	M4(see Fig
1900	35.76	0.08936	(AWF -5 dB)	(AWF -5 dB)	B.54)
WCDMA	37.82	0.06257	M4	M4	M4(see Fig
850	37.02	0.06257	(AWF 0 dB)	(AWF 0 dB)	B.55)
WCDMA	14.65	0.02705	M4	M4	M4(see Fig
1900	14.65	0.03795	(AWF 0 dB)	(AWF 0 dB)	B.56)



## 12 ANSI C 63.19-2007 LIMITS

AWF: Articulation Weighting Factor

Standard	Technology	AWF
TIA/EIA/IS-2000	CDMA	0
TIA/EIA-136	TDMA (50 Hz)	0
J-STD-007	GSM (217 Hz)	-5
T1/T1P1/3GPP	UMTS (WCDMA)	0
iDEN	TDMA (22 Hz and 11 Hz)	0

Table 1: Telephone near-field categories in linear units

Category		Telephone RF parameters < 960 MHz					
Near field	AWF	E-field emis	sions	H-field emiss	H-field emissions		
Catagon, M1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m		
Category M1	<b>-</b> 5	473.2 to 841.4	V/m	1.43 to 2.54	A/m		
Catagon, MO	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m		
Category M2	<b>–</b> 5	266.1 to 473.2	V/m	0.80 to 1.43	A/m		
Cotogon, M2	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m		
Category M3	<b>–</b> 5	149.6 to 266.1	V/m	0.45 to 0.80	A/m		
Catagon, MA	0	< 199.5	V/m	< 0.60	A/m		
Category M4	<b>-</b> 5	< 149.6	V/m	< 0.45	A/m		
Category		Telephone RF parameters > 960 MHz					
Near field	AWF	E-field emis	sions	H-field emiss	ions		
Cataman M4	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m		
Category M1	<b>-</b> 5	149.6 to 266.1	V/m	0.45 to 0.80	A/m		
Cata nam (MO	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m		
Category M2	<b>-</b> 5	84.1 to 149.6	V/m	0.25 to 0.45	A/m		
CotogomyMa	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m		
Category M3	<b>-</b> 5	47.3 to 84.1	V/m	0.14 to 0.25	A/m		
	0	< 63.1	V/m	< 0.19	A/m		
Category M4	•						



# **13 MEASUREMENT UNCERTAINTY**

No.	Error source	Туре	Uncertain ty Value	Prob.	k	C <sub>i</sub>	C <sub>i</sub>	Standard Uncertainty	Standard Uncertainty	Degree of freedom	
			(%)	Dist.		<b>E</b>	Η,	(%) u' <sub>i</sub> (%) E	(%) $u_i^{'}$ (%) H	V <sub>eff</sub> or v <sub>i</sub>	
Meas	Measurement System										
1	Probe Calibration	В	5.	N	1	1	1	5.1	5.1	∞	
2	Axial Isotropy	В	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞	
3	Sensor Displacement	В	16.5	R	$\sqrt{3}$	1	0.145	9.5	1.4	∞	
4	Boundary Effects	В	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	8	
5	Linearity	В	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	8	
6	Scaling to Peak Envelope Power	В	2.0	R	$\sqrt{3}$	1	1	1.2	1.2	8	
7	System Detection Limit	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	8	
8	Readout Electronics	В	0.3	N	1	1	1	0.3	0.3	8	
9	Response Time	В	0.8	R	$\sqrt{3}$	1	1	0.5	0.5	∞	
10	Integration Time	В	2.6	R	$\sqrt{3}$	1	1	1.5	1.5	8	
11	RF Ambient Conditions	В	3.0	R	$\sqrt{3}$	1	1	1.7	1.7	8	
12	RF Reflections	В	12.0	R	$\sqrt{3}$	1	1	6.9	6.9	8	
13	Probe Positioner	В	1.2	R	$\sqrt{3}$	1	0.67	0.7	0.5	8	
14	Probe Positioning	А	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	8	
15	Extra. And Interpolation	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	8	
Test	Sample Related										
16	Device Positioning Vertical	В	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	8	
17	Device Positioning Lateral	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞	
18	Device Holder and Phantom	В	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞	
19	Power Drift	В	5.0	R	$\sqrt{3}$	1	1	2.9	2.9	∞	



Pha	Phantom and Setup related									
20s	20s Phantom Thickness B 2.4 R √3 1 0.67 1.4 0.9 ∞									
Coml	bined standard uncertainty	(%)						14.7	10.9	
	Expanded uncertainty (confidence interval of 95 %) $u_e = 2u_c \qquad \qquad N \qquad \qquad k=2 \qquad \qquad 29.4 \qquad \qquad 21.8$									

## **14 MAIN TEST INSTRUMENTS**

**Table 2: List of Main Instruments** 

No.	Name	Туре	Serial Number	Calibration Date	Valid Period
01	Signal Generator	E4438C	MY49071430	February 08, 2013	One Year
02	Power meter	NRVD	102196	March 15, 2013	One year
03	Power sensor	NRV-Z5	100596	March 15, 2015	One year
04	Amplifier	60S1G4	0331848	No Calibration Re	quested
05	E-Field Probe	ER3DV6	2272	January 21, 2013	One year
06	H-Field Probe	H3DV6	6103	January 21, 2013	One year
07	HAC Dipole	CD835V3	1149	January 15, 2013	One year
80	HAC Dipole	CD1880V3	1135	January 15, 2013	One year
09	BTS	E5515C	MY50263375	January 30, 2013	One year
10	DAE	SPEAG DAE4	777	February 22, 2013	One year

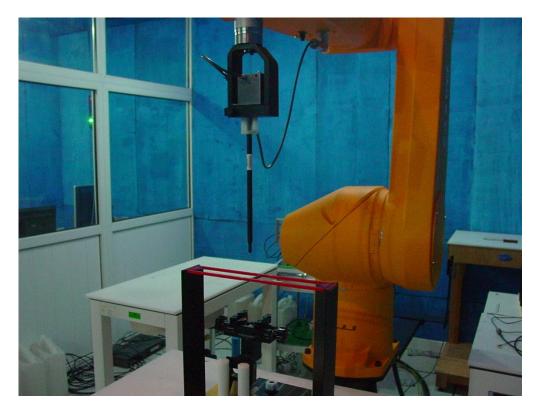
## 15 CONCLUSION

The HAC measurement indicates that the EUT complies with the HAC limits of the ANSI C63.19-2007. The total M-ratings are **M4.** 

\*\*\*END OF REPORT BODY\*\*\*



# **ANNEX A TEST LAYOUT**



Picture A1: HAC RF System Layout



## ANNEX B TEST PLOTS

## HAC RF E-Field GSM 850 High

Date: 2014-1-4

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.6°C

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 42.72 V/m; Power Drift = -0.02 dB

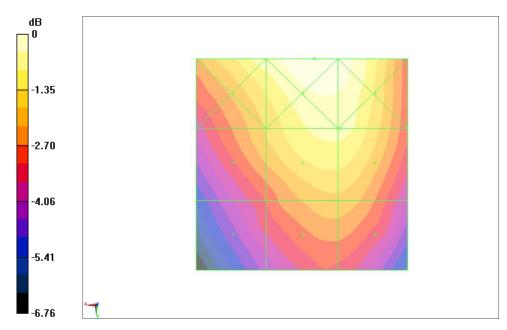
PMR not calibrated. PMF = 2.875 is applied.

E-field emissions = 109.2 V/m

Near-field category: M4 (AWF -5 dB)

PMF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 <b>M4</b>
110.6 V/m	117.7 V/m	116.1 V/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
96.14 V/m	109.2 V/m	109.2 V/m
Crid 7 MA	C : 10 N/A	C : 1 0 3 4 4
Gria / 1 <b>V14</b>	Gria 8 M4	Grid 9 <b>M4</b>



0 dB = 117.7 V/m = 41.42 dBV/m

Fig B.1 HAC RF E-Field GSM 850 High



### HAC RF E-Field GSM 850 Middle

Date: 2014-1-4

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.6°C

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 44.92 V/m; Power Drift = -0.09 dB

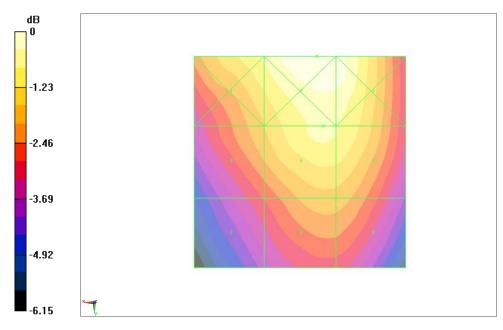
PMR not calibrated. PMF = 2.875 is applied.

E-field emissions = 111.3 V/m

Near-field category: M4 (AWF -5 dB)

#### PMF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
111.2 V/m	120.8 V/m	118.2 V/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
100.0 V/m	111.3 V/m	110.4 V/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
l	00 44 77/	98.14 V/m



0 dB = 120.8 V/m = 41.64 dBV/m

Fig B.2 HAC RF E-Field GSM 850 Middle



### **HAC RF E-Field GSM 850 Low**

Date: 2014-1-4

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.6°C

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

## E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device 3/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 41.40 V/m; Power Drift = -0.07 dB

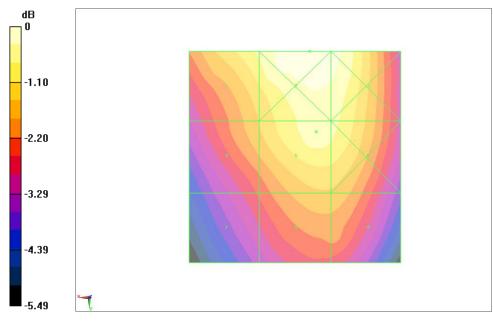
PMR not calibrated. PMF = 2.875 is applied.

E-field emissions = 104.4 V/m

Near-field category: M4 (AWF -5 dB)

PMF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
101.4 V/m		
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
92.54 V/m	104.4 V/m	102.0 V/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 M4
82.18 V/m	91.92 V/m	91.81 V/m



0 dB = 109.3 V/m = 40.77 dBV/m

Fig B.3 HAC RF E-Field GSM 850 Low